NSN 5961-01-391-3735

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-391-3735 **Inclosure Material:** Ceramic **Overall Length:** 0.990 inches **Overall Height:** 0.560 inches **Overall Width:** 0.545 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-254aa **Response Time:** 35.0 nanoseconds all semiconductor device diode **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, instantaneous all semiconductor device diode and 100.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 40.00 amperes forward current, average absolute all semiconductor device diode and 400.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Terminal areas iaw mil-std-2000 para. 5.4.17.2 gold **Precious Material:** Gold **Test Data Document:** 35351-171280 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:**

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Demilitarization: Yes - demil/mli